RoHS

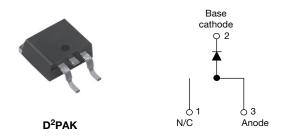
HALOGEN

FREE



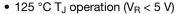
Vishay Semiconductors

High Performance Schottky Rectifier, 19 A



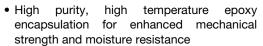
PRODUCT SUMMARY	1
Package	D ² PAK
I _{F(AV)}	19 A
V_{R}	15 V
V _F at I _F	0.36 V
I _{RM} max.	522 mA at 100 °C
T _J max.	125 °C
Diode variation	Single die
E _{AS}	6.75 mJ

FEATURES





- Ultralow forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability



- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-19TQ015SPbF Schottky rectifier has been optimized for ultralow forward voltage drop specifically for the OR-ing of parallel power supplies. The proprietary barrier technology allows for reliable operation up to 125 °C junction temperature. Typical applications are in parallel switching power supplies, converters, reverse battery protection, and redundant power subsystems.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	Rectangular waveform	19	A			
V _{RRM}		15	V			
I _{FSM}	t _p = 5 μs sine	700	А			
V _F	19 A _{pk} , T _J = 75 °C	0.32	V			
TJ	Range	-55 to +125	°C			

VOLTAGE RATINGS			
PARAMETER	SYMBOL	VS-19TQ015SPbF	UNITS
Maximum DC reverse voltage	V_{R}	15	V
Maximum working peak reverse voltage	V_{RWM}	15	V

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDI	TIONS	VALUES	UNITS
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 80 °C,	19	А	
Maximum peak one cycle non-repetitive surge current	I=	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with	700	А
See fig. 7	I _{FSM}	10 ms sine or 6 ms rect. pulse	rated V _{RRM} applied	330	A
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 1.50 \text{A}, L = 6 \text{m}$	ηΗ	6.75	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero Frequency limited by T _J maximu	o in 1 µs um V _A = 3 x V _R typical	1.50	А



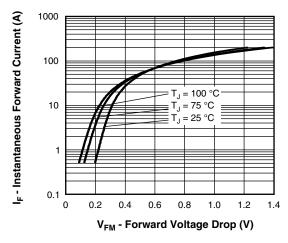
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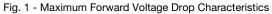
ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS
		19 A	T _{.1} = 25 °C	0.36	
Maximum forward voltage drop See fig. 1	V _{FM} ⁽¹⁾	38 A	1J=25 C	0.46	V
	V FM (')	19 A	T 75 00	0.32	
		38 A	- T _J = 75 °C	0.43	
		T _J = 100 °C, V _R = 12 V		465	mA
Maximum reverse leakage current	I _{RM} ⁽¹⁾	$T_J = 100 ^{\circ}\text{C}, V_R = 5 \text{V}$		285	
See fig. 2		T _J = 25 °C	V DetectV	10.5	IIIA
		T _J = 100 °C	V _R = Rated V _R	522	
Maximum junction capacitance	C _T	V _R = 5 V _{DC} (test signal ran	ge 100 kHz to 1 MHz), 25 °C	2000	pF
Typical series inductance	L _S	Measured lead to lead 5 r	Measured lead to lead 5 mm from package body		
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs

Note

 $^{^{(1)}\,}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	MBOL TEST CONDITIONS		UNITS	
Maximum junction tempe	rature range	TJ		-55 to +125	°C	
Maximum storage temper	rature range	T _{Stg}		-55 to +150	C	
Maximum thermal resistance, junction to case		R _{thJC}	DC operation See fig. 4	1.50 °C/V		
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50	C/VV	
Annyayinasta waight				2	g	
Approximate weight				0.07	OZ.	
minimum				6 (5)	kgf · cm	
Mounting torque maximum				12 (10)	(lbf·in)	
Marking device			Case style D ² PAK	19TQ	015S	





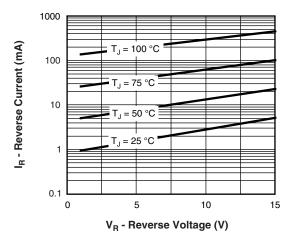


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



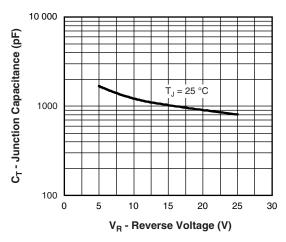


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

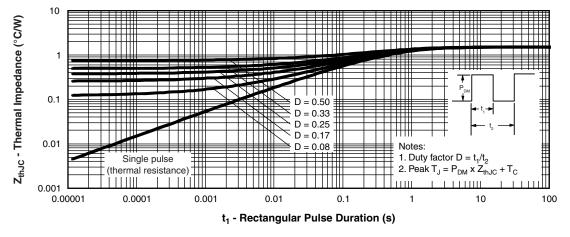


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

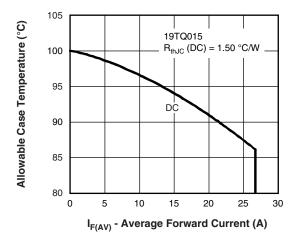


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

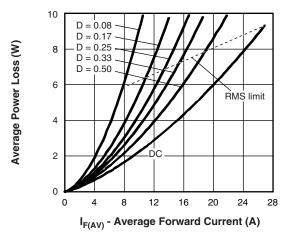
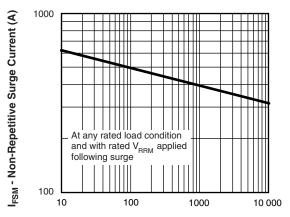


Fig. 6 - Forward Power Loss Characteristics

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t_p - Square Wave Pulse Duration (μs)

Fig. 7 - Maximum Non-Repetitive Surge Current

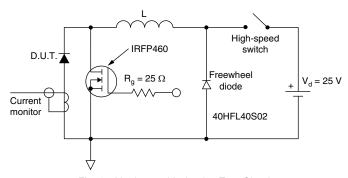


Fig. 8 - Unclamped Inductive Test Circuit

ORDERING INFORMATION TABLE

Device code	vs-	19	т	Q	015	s	TRL	PbF
	1	2	3	4	5	6	7	8
	1 -	Vish	nay Sen	niconduc	ctors pro	oduct		
	2 -	Cur	rent rati	ng (19 A	A)			
	3 -	Circ	cuit conf	iguratior	n: T = T	O-220		
	4 -	Sch	ottky "C	" series				
	5 -	Volt	tage rati	ng (015	= 15 V))		
	6 -	S =	D ² PAK					
	7 -	• N	one = tu	be (50 p	oieces)			
		• TI	RL = tap	e and re	eel (left	oriente	d)	
		• TI	RR = ta _l	oe and r	eel (righ	nt orient	ed)	
	8 -	PbF	= lead	(Pb)-fre	e			

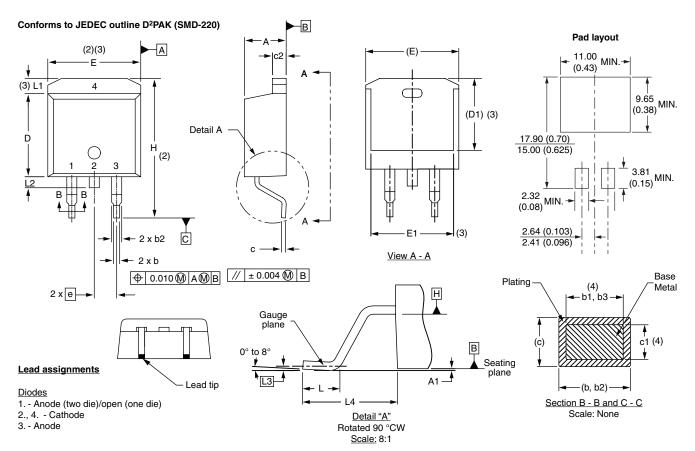
LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95014			
Part marking information	www.vishay.com/doc?95008			
Packaging information	www.vishay.com/doc?95032			
SPICE model	www.vishay.com/doc?96005			



Vishay High Power Products

D²PAK, TO-262

DIMENSIONS FOR D²PAK in millimeters and inches



	MILLIM	IETERS	INC	HES	
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STINIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
Е	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100 BSC		
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25 BSC		0.010	BSC	
L4	4.78	5.28	0.188	0.208	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- $^{(3)}\,$ Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch

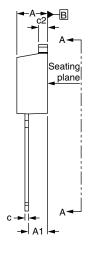
(7) Outline conforms to JEDEC outline TO-263AB

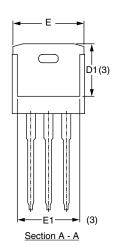
Vishay High Power Products

D²PAK, TO-262



DIMENSIONS FOR TO-262 in millimeters and inches





⊕ 0.010**⋒**|A**⋒**|B

Lead assignments



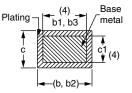
Diodes

-3 x b2 --3 x b

1. - Anode (two die)/open (one die)

2., 4. - Cathode

3. - Anode



Section B - B and C - C Scale: None

OVMDOL	MILLIM	ETERS	INC	HES	NOTES
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
Е	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54	BSC	0.100) BSC	
L	13.46	14.10	0.530	0.555	
L1	-	1.65	-	0.065	3
L2	3.56	3.71	0.140	0.146	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Controlling dimension: inches

(6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline



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